

ORCA - Online Research @ Cardiff

This is an Open Access document downloaded from ORCA, Cardiff University's institutional repository:https://orca.cardiff.ac.uk/id/eprint/139393/

This is the author's version of a work that was submitted to / accepted for publication.

Citation for final published version:

Guo, Tianxiao, Yang, Nianjun, Yang, Bing, Schulte, Anna, Jin, Qun, Koch, Ulrike, Mandal, Soumen, Engelhard, Carsten, Williams, Oliver A., Schönherr, Holger and Jiang, Xin 2021. Electrochemistry of nitrogen and boron bi-element incorporated diamond films. Carbon 178, pp. 19-25.

10.1016/j.carbon.2021.02.062

Publishers page: http://dx.doi.org/10.1016/j.carbon.2021.02.062

Please note:

Changes made as a result of publishing processes such as copy-editing, formatting and page numbers may not be reflected in this version. For the definitive version of this publication, please refer to the published source. You are advised to consult the publisher's version if you wish to cite this paper.

This version is being made available in accordance with publisher policies. See http://orca.cf.ac.uk/policies.html for usage policies. Copyright and moral rights for publications made available in ORCA are retained by the copyright holders.



1	Electrochemistry of Nitrogen and Boron
2	Bi-element Incorporated Diamond Films
3	Tianxiao Guo, a Nianjun Yang, a* Bing Yang, b Anna Schulte, c Qun Jin, a Ulrike Koch, d
4	Rainer Bornemann, e Soumen Mandal, f Carsten Engelhard, d Oliver A. Williams, f
5	Holger Schönherr, ^c and Xin Jiang ^{a, *}
6	^a Institute of Materials Engineering, University of Siegen, Siegen 57076, Germany
7	^b Shenyang National Laboratory for Materials Science, Institute of Metal Research
8	(IMR), Chinese Academy of Science (CAS), No. 72 Wenhua Road, Shenyang
9	110016, China
LO	^c Physical Chemistry I, Department of Chemistry and Biology and Research Center of
l1	Micro and Nanochemistry and Engineering (Cµ), University of Siegen, Siegen 57075,
12	Germany
L3	^d Analytical Chemistry, Department of Chemistry and Biology and Research Center
L4	of Micro and Nanochemistry and Engineering (Cµ), University of Siegen, Siegen
L 5	57075, Germany
16	^e Institute for High Frequency and Quantum Electronics, School of Science and
L7	Technology, University of Siegen, Siegen, Siegen 57076, Germany
18	^f School of Physics and Astronomy, Cardiff University, Cardiff CF24 3AA, UK
19	* Corresponding author. Tel: 0049271 7402531 (N. Yang); 0049 271740-2966 (X.
20	Jiang)
21	E-mail: xin.jiang@uni-siegen.de (X. Jiang); nianjun.yang@uni-siegen.de (N. Yang)

Abstract (188 words)

1

19

20 21

Boron doped diamond (BDD) has been widely used in various electrochemical fields, 2 3 due to its unique physical and chemical properties. However, the investigation of the electrochemistry of bi-element incorporated diamond, especially the variation of 4 surface components after nitrogen incorporation into BDD and the corresponding 5 electron transfer of inner-sphere and outer-sphere redox probes is still lacking. Here, 6 the electrochemistry of nitrogen and boron bi-element incorporated diamond (NBD) is 7 thus investigated in both inner and outer redox systems, namely in [Fe(CN)₆]^{3-/4-} and 8 [Ru(NH₃)₆]^{3+/2+} solutions. On the NBD electrode, enhanced electrochemical responses 9 10 are achieved for both outer- and inner-sphere redox reactions. Such enhancement originates from the enrichment of C=O groups and the increased amount of sp² species 11 12 in the NBD film. Moreover, the nitrogen and boron atoms incorporated in diamond 13 modulate the surface polarities and the electronic states of diamond. Based on the 14 enhanced and stable capacitance of the NBD electrode, its electrochemical energy 15 applications are explored by assembling its supercapacitor as a case study. This work 16 reveals the influence of sp² species and oxygen-contained function group on the 17 electrochemistry of bi-element incorporated diamond films and reveals their potential 18 electrochemical applications.

Keywords: Electrochemistry, nitrogen and boron-doped diamond, sp²-carbon

1. Introduction

1

2 The electrochemistry of doped diamond, especially p-type diamond or boron doped 3 diamond (BDD) has been widely investigated in the past decades. As an excellent electrode material, BDD has been utilized for electrochemical sensors [1, 2], 4 supercapacitor construction [3-5], CO₂ reduction [6, 7], nitrogen redox reaction (NRR) 5 [8], and wastewater treatment [9, 10]. These applications originate from the unique 6 7 features of a BDD electrode, such as its low background current, wide potential 8 windows in different media, and long-term durability. Boron atoms doped in diamond realize the transformation of diamond from an intrinsic insulator to a semiconductor 9 10 [11], and finally to a metal-like conductor once the boron doping level increases above to 10²⁰ cm⁻³ [12]. It is well-known that the diamond crystal structure, surface 11 termination, and sp² species or sp²/sp³ ratio on the diamond surface play significant 12 13 roles to determine the electrochemical features of a BDD electrode. For example, a rough BDD surface promotes the transformation of the Faradaic reactions from kinetic-14 15 to diffusion-control together with enhanced charge transfer rates [13, 14]. The surface 16 (e.g., hydrogen, oxygen) terminations of a BDD film influence the kinetics of Faradaic reactions on the diamond surface because these terminations possess significant 17 18 difference in their electronic structures [15-17]. In this regard, the electrochemistry of 19 BDD films containing various amounts of sp² carbon has been also extensively studied, although their quality is much reduced and their background currents are much enhance 20 21 [18]. To further boost the performance of diamond films in the fields of energy and

1 catalysis applications, diamond composite structures have been designed, for instance 2 to assemble battery-like supercapacitors by use of aligned carbon nanofiber coated 3 BDD [4], to achieve an efficient methanol oxidation reaction (MOR) using nanoporous platinum particles coated BDD [19]. 4 On the other hand, electrochemistry of n-type diamond, namely diamond films doped 5 with nitrogen or phosphorus atoms has also attracted much attention. Nitrogen doping 6 7 or incorporation into carbon materials has also been confirmed as a fruitful strategy to promote the electrocatalytic activity of these carbon materials. The pyridinic N atoms 8 create Lewis basic sites that are actually regarded as the catalytic active sites [20, 21]. 9 10 For example, a nitrogen doped diamond (NDD) film is proved to contain N-sp³ 11 components, namely electrocatalytic active sites [22, 23]. In this context, a NDD film 12 exhibits high overpotential for the hydrogen evolution reaction (HER) and has been applied for highly efficient CO₂ reduction [24, 25]. 13 14 We are interested in the electrochemistry of bi-element incorporated diamond films. 15 Compared with diamond films doped with a single dopant, diamond films with dual 16 dopants are expected to regulate the electronic structure of diamond materials and 17 eventually exhibit faster electron transfer rates and more active sites for catalysis [26-18 28]. Such enhanced electrochemical performance stems from the synergistic effects of 19 two different and incorporated atoms in the diamond film. One recent example is the

application of nitrogen and boron co-doped diamond (NBD) film for the efficient CO2

reduction [29]. The NBD film with optimized contents of nitrogen and boron dopants

20

1 exhibited comparable performance toward oxygen reduction reaction (ORR) to the Pt/C catalyst, including a high current density for ORR and long-term durability of the 2 3 system [30]. In spite of these successful catalytic applications of these bi-element incorporated diamond films, the electrochemistry of the NBD films has been seldom 4 investigated. For example, the variation of surface components in the NBD films and 5 their influence on the electron transfer rates of both inner-sphere and outer-sphere redox 6 7 systems have not been clarified up to now. Moreover, reports about the applications of bi-element incorporated diamond films for energy storage are still missing in the 8 literature, although BDD and its composites are shown to be promising electrode 9 10 candidates for the assembly of supercapacitors [4, 31, 32]. Therefore, this contribution 11 deals with the electrochemistry of the NBD films that are grown by a microwave plasma enhanced chemical vapor deposition (MPCVD) method. After the characterization of 12 13 this NBD film with different techniques, its electrochemical responses are studied in both [Fe(CN)₆]^{3-/4-} and [Ru(NH₃)₆]^{3+/2+} redox systems, which are further compared with 14 15 the BDD electrode. As a case study of the energy applications of these NBD films, a 16 supercapacitor is assembled and investigated.

17

18

19

2. Experiment section

- 2.1 Materials synthesis and characterization
- 20 The NBD and BDD films were grown on the Si (100) wafers using a MPCVD method
- 21 [33-35]. The detailed growth parameters are listed in **Table S1**.

The SEM images of the as-grown NBD and BDD films were recorded with a field 1 2 emission scanning electron microscope (FESEM, Zeiss ultra55, Germany). The 3 transmission electron microscopy (TEM, FEI G² F20) was employed to characterize the defects the crystalline defects in the as-grown NBD and BDD films. The surface 4 chemical composition of these as-grown diamond films was analyzed by X-ray 5 photoelectron spectroscopy (S-probe ESCA SSX-100s, Surface Science Instruments, 6 7 USA) with an Al Ka radiation of 200 W. The survey spectra were measured from 0 to 1200 eV with a resolution of 1 eV at a spot size of 800 μm². The high resolution spectra 8 were collected with a resolution of 0.1 eV at a spot size of 300 µm². The Raman spectra 9 10 of the as-grown diamond films were collected on a homemade Raman Instrument 11 equipped with a 532-nm laser. A time-of-flight secondary ion mass spectrometer (ToF-SIMS IV, ION-TOF GmbH, Germany) was used to map the dopants in these as-grown 12 13 diamond films, such as the contents of nitrogen and boron atoms in the NBD films as 14 well as boron atom in the BDD film. For these mapping experiments, a 25-keV Bi⁺ 15 primary ion beam was employed to bombard the diamond surface within an area of 300 16 \times 300 μm^2 . 18 2.2 Electrochemical measurements

17

21

Electrochemical measurements of the as-grown NBD and BDD films were conducted 19 20 on a CHI660e workstation (Shanghai Chenhua Inc., China) using a three-electrode cell,

where an Ag/AgCl (3MKCl) electrode acted as reference electrode, a Pt wire as counter

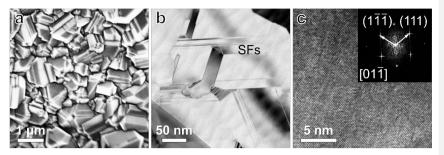
1	electrode, a NBD film or a BDD film as working electrode. The geometric area of a
2	working electrode was $0.05\mathrm{cm^2}$. To investigate the electrochemical performance of the
3	NBD and BDD films, their cyclic voltammograms (CVs) were recorded in either 1 mM
4	K ₃ [Fe(CN) ₆] or [Ru(NH ₃) ₆]Cl ₃ dissolved in 1 M KCl aqueous solution. The
5	investigation of the pseudocapacitive behavior of the post-treated NBD and BDD films
6	was carried out by means of cyclic voltammetry at different scan rates and by means of
7	the galvanostatic charge/discharge (GCD) method at different current densities. The
8	post-treatment was conducted in the mixture of H_2SO_4 and HNO_3 (V/V = 3:1) for 30
9	min. In this way, these diamond films were found to exhibit better wettability in the
10	electrolytes. The electrolyte used for the assemble of a supercapacitor was 0.05 M
11	K ₃ Fe(CN) ₆ /K ₄ Fe(CN) ₆ dissolved in 1.0 M Na ₂ SO ₄ solution. The specific capacitances
12	were calculated according to the reported methods [4, 36]. The calculation of the
13	contribution of the capacitive current was based on the equation of $i(V) = k_1 v + k_2 v^{1/2}$
14	[37, 38]. Here, $i(V)$ is the related current at the potential of V, v is scan rate, $k_2v^{1/2}$ and
15	k_1v are related to diffusion-controlled and capacitive-controlled, respectively. Note that
16	the capacitive current can be also evaluated directly from the cyclic voltammograms
17	(CVs) or the GCD curves in the blank solutions (namely those containing only
18	supporting electrolytes).

20

3. Results and discussion

21 3.1 Characterization of the NBD films

The morphologies of the as-grown BDD and NBD films were analyzed by electron 1 microscopy. From the typical SEM images of the NBD (Figure 1a) and BDD (Figure 2 3 S1) films, one can see clearly that these films exhibit typical and similar morphology to that of polycrystalline diamond films. Their grain sizes are in the range of 0.4 - 1.2 4 μm. The cross-sectional SEM images of the NBD and BDD films (Figure S2) reveal 5 their thickness to be about 1.5 µm. To check out crystalline defects on these films, the 6 7 TEM images of the NBD film were recorded (Figure 1b, 1c), where twin boundaries and stacking faults are observed. The presence of these defects is caused by the 8 incorporation of both nitrogen and boron atoms into the diamond film. At selected 9 10 locations for TEM imaging experiments, it seems to be that the crystalline defects of the NBD film are reduced, compared to the BDD film (Figure S1). Meanwhile, the 11 12 crystalline quality of a NBD film seems to be improved and the {100} texture of 13 diamond is promoted [39]. In a high-resolution TEM (HRTEM) image of a NBD film 14 (Figure 1c), the atomic structure of the NBD film can be clearly seen along the [01-1] 15 zone axis. According to the inset of fast Fourier transformation (FFT), the diffraction 16 spots reveal spacings of 0.206 and 0.18 nm. These spacings correspond to the (111) and 17 (200) planes of diamond phase, respectively. Consequently, the as-grown NBD and 18 BDD films exhibit high crystallinity.



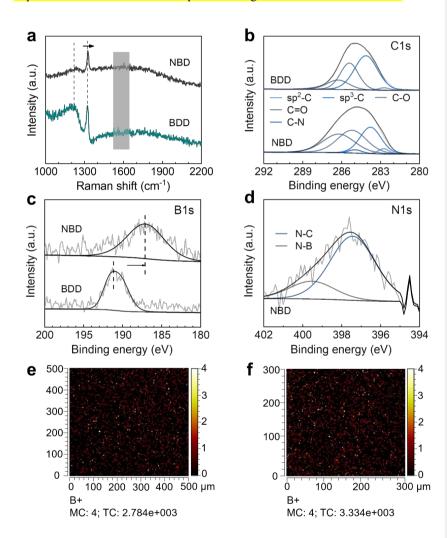
2 Figure 1. (a) SEM, (b) low-magnification TEM and (c) HRTEM images of a NBD film.

- 3 The inset in (c) is the corresponding fast Fourier transformation (FFT) of the HRTEM
- 4 image.

- 6 The Raman spectra of the as-grown NBD and BDD films were also recorded (Figure
- 7 **2a**). In both spectra, the typical Raman peak of diamond is seen around 1320 cm⁻¹. The
- 8 Lorentzian peak located around 1200 cm⁻¹ is classified as the symmetry breaking of the
- 9 diamond lattice. The spectrum of a NBD film displays a finite blueshift, resulting from
- 10 a higher bond energy when nitrogen and boron atoms are bi-element incorporated in
- the diamond lattice [40]. Moreover, both Raman spectra of the as-grown NBD and BDD
- films reveal a broad peak around at 1580 cm⁻¹. It is known as the G band that results
- from the bond stretching of sp² atoms in both rings and chains.
- 14 To determine the surface chemical bonding of the as-grown NBD and BDD films, their
- survey and C1s XPS spectra were recorded and compared (Figure S3 and Figure 2b).
- In both XPS spectra, four peaks centered at 282.8, 284.1, 285.2, and 286.3 eV are
- attributed to sp² and sp³ hybridized carbon species, as well as carbon bonded to oxygen
- as C-O and as C=O, respectively [41, 42]. The peak located around 284.8 eV in the

1 NBD film corresponds to carbon bonded to nitrogen. Furthermore, it can be seen that the NBD film reveals a substantially higher sp²/sp³ ratio than the BDD film together 2 3 with an increased fraction of carbon in C=O and C-O bonds (Table S2). The nitrogen atoms incorporated into diamond are expected to be three-fold coordinated in the 4 amorphous/disordered regions with the remaining electrons in a lone pair configuration. 5 In other words, the nitrogen atoms incorporated into diamond promotes the formation 6 7 of sp2 carbon [43, 44]. Under such conditions, nitrogen incorporation into diamond 8 tends to change the bonding, instead of being assimilated by the diamond lattice that is not the intrinsic of electronic dopant. Figure 2c shows that the B1s peak of the NBD 9 10 film is shifted to a lower binding energy compared to the B1s peak of the BDD film. Presumably, this is due to the formation of B–N bonds in the NBD film. In the N1s 11 12 XPS spectrum of the NBD film (Figure 2d), two peaks are detected at 399.7 and 397.5 eV, which are attributed to nitrogen atoms bonded to carbon and to boron, respectively 13 [25, 29, 30]. In the XPS spectrum of the BDD film, no N1s peak was detected. The 14 15 ratios of nitrogen to carbon and boron to carbon were estimated from the high resolution 16 XPS spectra of the NBD film. They are 0.013 and 0.008, respectively. Similarly, the ratio of boron to carbon in the BDD film is 0.008. Furthermore, boron atoms are found 17 18 to be homogeneously and uniformly distributed throughout the film, as confirmed from 19 secondary ion mass spectrometry (SIMS) mappings of doped boron atoms in the NBD and BDD films (Figure 2e, 2f, S4). Surprisingly, nitrogen was not detectable with the 20 current SIMS setup, due to isobaric interferences from carbon species with similar 21

- mass-to-charge ratios (m/z) (Figure S4 a-b). Meanwhile, the content of incorporated
- 2 nitrogen in the NBD film under investigation is presumably not very high (e.g., less
- 3 than 1018 atoms cm⁻³) and close to or at the detection limit of our SIMS setup. In the
- 4 future, a better primary beam intensity and improved vacuum will help to achieve
- 5 improved detection limits for incorporated nitrogen atoms in these NBD films.



- 1 Figure 2. (a) Raman spectra of the NBD and BDD films; their C1s(b), B1s(c) and N1s
- 2 (d) XPS spectra; SIMS mapping of boron atoms doped in the NBD film directly (e) and
- 3 after 30 sec sputtering with Argon for cleaning the surface (f) in the positive ion mode
- 4 (MC max counts per pixel, TC total counts).

- 3.2 Electrochemical properties of the NBD films
- 7 The electrochemistry of the as-grown NBD and BDD films was then investigated and
- 8 compared. Both inner and outer redox systems were used, namely 1 mM [Ru(NH₃)₆]Cl₃
- 9 (Figure 3a) and 1 mM K_3 [Fe(CN)₆] (Figure 3b) dissolved in 1 M KCl aqueous solution.
- 10 For the [Ru(NH₃)₆]Cl₃ redox system (Figure 3a), the NBD electrode shows a higher
- peak current (e.g., a cathodic peak current, $I_c = 140.22 \,\mu\text{A cm}^2$) and a bigger difference
- of peak separation ($\Delta E_p = 72 \text{ mV}$) than the BDD electrode ($I_c = 131.08 \,\mu\text{A cm}^{-2}$ and
- 13 $\Delta E_p = 58 \text{ mV}$). For the K₃[Fe(CN)₆] redox system (**Figure 3b**), I_c rises from 145.5 μ A
- 14 cm⁻² on a BDD electrode to 162.34 μA cm⁻² on a NBD electrode. However, a NBD
- electrode shows a bigger ΔE_p (84 mV) than a BDD electrode (75 mV). As inner-sphere
- redox probes, the electrode kinetics of [Fe(CN)₆]^{3-/4-} is known to be tightly related to
- 17 surface terminations or surface functional groups of a diamond electrode [42]. Different
- 18 from the [Fe(CN)₆]^{3-/4-} inner-sphere redox system, the electron transfer and the
- 19 electrode kinetic of the outer-sphere $[Ru(NH_3)_6]^{3+/2+}$ redox system is influenced mainly
- 20 by the carrier density (e.g., the amount of sp² carbon species) of the diamond films [17,
- 21 45]. According to the growth parameters, the NBD and BDD films feature high boron

1 densities or low electricity that is favorable for fast electron transfer processes [16]. However, a higher amount of boron atoms is expected to be doped in the NBD film 2 3 than that in a BDD film. This originates from the "enhanced incorporation" effect of nitrogen in the gas mixture. The XPS results showed that the NBD film is enriched in 4 C=O bonds compared to the BDD film. These surface oxygen groups on the electrodes 5 thus block electrochemical active sites of the NBD electrode and/or bring more 6 7 repulsive force for the negatively charged [Fe(CN)₆]^{3-/4-} redox probes to interact with the NBD electrode. The electron transfer process of [Fe(CN)₆]^{3-/4-} redox probes is thus 8 inhibited on the NBD surface, eventually leading to reduced peak currents. On the other 9 10 hand, the increased amount of sp² species after the nitrogen incorporation into a BDD 11 film leads to the decrease of carrier density that promotes the electron transfer of outersphere $[Ru(NH_3)_6]^{3+/2+}$ redox probes and finally more pronounced peak currents. 12

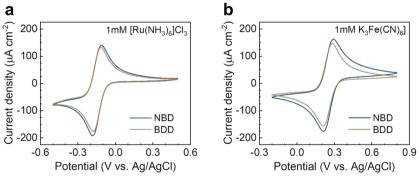


Figure 3. Cyclic voltammograms of the NBD and BDD electrodes at a scan rate of 0.1 V s⁻¹ in (a) 1 mM $[Ru(NH_3)_3]Cl_3$ and (b) 1 mM $K_3Fe(CN)_3$ dissolved in 0.5 M KCl solution.

13

14

15

16

3.3 Electrochemical applications of the NBD films

1

2 To explore the electrochemical applications of such NBD films, they were utilized as 3 the capacitor electrodes for the supercapacitor assembly. In such a case study, these NBD films were wet-chemically treated since such post-treatment improved much their 4 5 wettability. Here, a redox-electrolyte enhanced supercapacitor was fabricated [4, 46]. From the CVs of the NBD and BDD films recorded at different scan rates (Figure S6), 6 7 one can notice stable ΔE_p and I_c at all scan rates. These results indicate the perfect reversibility of the NBD and BDD films or these diamond capacitor electrodes in such 8 an electrolyte. Notice here that the ΔE_p values in Figure S5 are different from those in 9 10 Figure 3b, although the used redox electrolytes are same. This is because these diamond electrodes in Figure S5 were wet-chemically treated, while those in Figure 11 12 **3b** were the as-grown diamond films. In other words, different surface terminations on these electrodes affect significantly the kinetics of redox reactions on these diamond 13 electrodes [15-17]. The estimated capacitances of the NBD electrode are 87.7, 66.8, 14 15 39.4, and 26.8 mF cm⁻² at the scan rates of 10, 20, 50, and 100 mV s⁻¹, respectively. 16 Meanwhile, the galvanostatic charge/discharge (GCD) curves of the NBD and BDD electrodes (Figure 4a) also reveal good reversibility, as confirmed from the almost 17 18 equal charge and discharge times in these GCD curves. The calculated capacitances of 19 the NBD electrode (Figure 4b) are 98.9, 56, 28.7, and 14.9 mF s-1 at the current densities of 1, 2, 4, and 8 mA cm⁻², respectively. They are higher than those of a BDD 20 21 electrodes: 71.3, 39.7, 20.8, and 10.7 mF s⁻¹ at the current densities of 1, 2, 4, and 8 mA

cm⁻², respectively. The capacitive contribution of the NBD and BDD electrodes were 1 2 further calculated to explore the difference of the reaction kinetics between two 3 capacitor electrodes. Figure 4c presents the contribution ratios of capacitive-controlled and diffusion-controlled processes on the NBD and BDD electrodes. Both exhibit an 4 increased ratio of capacitive contribution with the enlargement of scan rate. Specifically, 5 the NBD electrode shows a higher capacitive contribution ratio than a BDD electrode. 6 7 This reveals the underlying essence of the better rate performance of the NBD electrode. The enhanced capacitance of the NBD electrode is because the incorporation of 8 nitrogen and boron atoms into diamond modulates the surface polarities and the 9 electronic of materials [47, 48]. For example, the charge-transfer resistance of the NBD 10 film, as estimated from its Nyquist plots (Figure S7) is 94 Ω , which is smaller than 11 that (143Ω) of the BDD film. 12 The long-term cycling stability of the BDD and NBD electrodes was further tested at 13 14 the current density of as high as 8 mA cm⁻². Although the NBD electrode exhibits a 15 higher capacitance than a BDD electrode, both electrodes show the similar cycling 16 stability even after 10000 GCD cycles (Figure 4d and Figure S8). All these results confirm the suitability of employing the NBD film for electrochemical energy storage 17 18 applications. Note that the surface of the post-treated NBD electrode is possible to be 19 re-activated electrochemically or by use of a plasma technique. The studies on the effect 20 of the surface terminations of the NBD electrode on their capacitive performance are 21 currently undergoing in our lab.

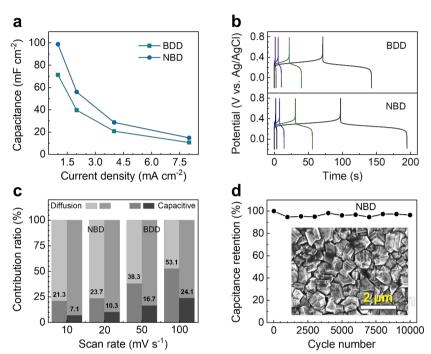


Figure 4. Capacitive performance of the NBD and BDD electrodes in 0.05 MFe(CN)₆³
14+1.0 M NaSO₄: (a) the GCD curves at the current densities of 1, 2, 4, and 8 mA cm²; (b) the variation of the specific capacitances with the current densities; (c) the contribution ratios of capacitive and diffusion capacity as a function of scan rates; (d) the capacitance retention at a current density of 8 mA cm². The inset shows the SEM image of the post-treated NBD electrode after 10000 GCD cycles.

4. Conclusion

The electrochemistry of nitrogen and boron bi-element incorporated diamond film is explored. The NBD electrode reveals better electrochemical responses in both inner-sphere $[Fe(CN)_6]^{3-/4}$ and outer-sphere $[Ru(NH_3)_6]^{3+/2+}$ redox systems, when compared

1 to a BDD electrode. The improved electrochemical performance of the NBD film is 2 related to the enrichment of C=O bonds and the increase amount of sp² species on the 3 NBD film. The bigger capacitance of the NBD electrode than that of a BDD mainly stems from that the incorporation of nitrogen and boron atoms into the diamond 4 modulates the surface polarities and the electronic structures of diamond. Moreover, a 5 higher amount of boron atoms in the NBD film is expected than that in the BDD film, 6 due to the "enhanced incorporation" effect of nitrogen in the gas mixture. Such an 7 enhanced capacitance of the NBD electrode extends its potential applications for 8 electrochemical energy storage. Future work has to be conducted on the effect of the 9 10 densities of incorporated atoms in the NBD film and the surface terminations of the NBD film on the electrochemistry of these bi-element incorporated diamond films. 11 12 Their further electrochemical energy storage (e.g., for SCs and batteries) and catalytic 13 applications (e.g., for water splitting and CO₂ reduction, nitrogen fixation) can be tried. 14 In summary, this work provides a new electrode material for future electrochemical 15 applications.

16

17

Acknowledgements

- 18 T. Guo acknowledges the financial support from the China Scholarship Council (No.
- 19 201906370017). N. Yang acknowledges funded by the Deutsche
- 20 Forschungsgemeinschaft (DFG, German Research Foundation) under the project
- 21 457444676. B. Yang acknowledges the financial support from the National Natural

- 1 Science Foundation of China (Grant No. 51872294). O. Williams acknowledges the
- 2 financial support of the European Research Council (ERC) Consolidator Grant
- 3 "SUPERNEMS" under the Project of 647471. Part of this work was performed at the
- 4 Micro- and Nanoanalytics Facility (MNaF) at the University of Siegen.

6 References

- 7 [1] A.J. Lucio, R.E. Meyler, M.A. Edwards, J.V. Macpherson, Investigation of sp²-
- 8 Carbon Pattern Geometry in Boron-Doped Diamond Electrodes for the Electrochemical
- 9 Quantification of Hypochlorite at High Concentrations, ACS sensors 5(3) (2020) 789-
- 10 797.
- 11 [2] N. Yang, H. Uetsuka, E. Osawa, C.E. Nebel, Vertically aligned diamond nanowires
- for DNA sensing, Angewandte Chemie International Edition 47(28) (2008) 5183-5185.
- 13 [3] Z. Jian, N. Yang, M. Vogel, S. Leith, A. Schulte, H. Schönherr, T. Jiao, W. Zhang,
- 14 J. Müller, B. Butz, Flexible Diamond Fibers for High-Energy-Density Zinc-Ion
- 15 Supercapacitors, Advanced Energy Materials (2020) 2002202.
- 16 [4] S. Yu, N. Yang, M. Vogel, S. Mandal, O.A. Williams, S. Jiang, H. Schönherr, B.
- 17 Yang, X. Jiang, Battery-like supercapacitors from vertically aligned carbon nanofiber
- 18 coated diamond: design and demonstrator, Advanced Energy Materials 8(12) (2018)
- 19 1702947.

- 1 [5] S. Yu, J. Xu, H. Kato, N. Yang, A. Schulte, H. Schönherr, X. Jiang, Phosphorus-
- 2 doped nanocrystalline diamond for supercapacitor application, ChemElectroChem 6(4)
- 3 (2019) 1088-1093.
- 4 [6] M. Tomisaki, S. Kasahara, K. Natsui, N. Ikemiya, Y. Einaga, Switchable product
- 5 selectivity in the electrochemical reduction of carbon dioxide using boron-doped
- 6 diamond electrodes, Journal of the American Chemical Society 141(18) (2019) 7414-
- 7 7420.
- 8 [7] K. Natsui, H. Iwakawa, N. Ikemiya, K. Nakata, Y. Einaga, Stable and highly
- 9 efficient electrochemical production of formic acid from carbon dioxide using diamond
- 10 electrodes, Angewandte Chemie 130(10) (2018) 2669-2673.
- 11 [8] B. Liu, Y. Zheng, H.-Q. Peng, B. Ji, Y. Yang, Y. Tang, C.-S. Lee, W. Zhang,
- 12 Nanostructured and Boron-Doped Diamond as an Electrocatalyst for Nitrogen Fixation,
- 13 ACS Energy Letters 5(8) (2020) 2590-2596.
- 14 [9] P. Nidheesh, G. Divyapriya, N. Oturan, C. Trellu, M.A. Oturan, Environmental
- 15 applications of boron-doped diamond electrodes: 1. Applications in water and
- wastewater treatment, ChemElectroChem 6(8) (2019) 2124-2142.
- 17 [10] C. Zhang, J. Wang, H. Zhou, D. Fu, Z. Gu, Anodic treatment of acrylic fiber
- 18 manufacturing wastewater with boron-doped diamond electrode: a statistical approach,
- 19 Chemical Engineering Journal 161(1-2) (2010) 93-98.
- 20 [11] Z. Teukam, J. Chevallier, C. Saguy, R. Kalish, D. Ballutaud, M. Barbé, F. Jomard,
- 21 A. Tromson-Carli, C. Cytermann, J.E. Butler, Shallow donors with high n-type

- 1 electrical conductivity in homoepitaxial deuterated boron-doped diamond layers,
- 2 Nature materials 2(7) (2003) 482-486.
- 3 [12] T. Yokoya, T. Nakamura, T. Matsushita, T. Muro, Y. Takano, M. Nagao, T.
- 4 Takenouchi, H. Kawarada, T. Oguchi, Origin of the metallic properties of heavily
- 5 boron-doped superconducting diamond, Nature 438(7068) (2005) 647-650.
- 6 [13] P. Lim, F. Lin, H. Shih, V. Ralchenko, V. Varnin, Y.V. Pleskov, S. Hsu, S. Chou,
- 7 P. Hsu, Improved stability of titanium based boron-doped chemical vapor deposited
- 8 diamond thin-film electrode by modifying titanium substrate surface, Thin Solid Films
- 9 516(18) (2008) 6125-6132.
- 10 [14] E. Brillas, C.A. Mart, Synthetic diamond films: preparation, electrochemistry,
- 11 characterization, and applications, John Wiley & Sons2011.
- 12 [15] Y. Takagi, K. Shiraishi, M. Kasu, H. Sato, Mechanism of hole doping into
- 13 hydrogen terminated diamond by the adsorption of inorganic molecule, Surface Science
- 14 609 (2013) 203-206.
- 15 [16] L.A. Hutton, J.G. Iacobini, E. Bitziou, R.B. Channon, M.E. Newton, J.V.
- 16 Macpherson, Examination of the factors affecting the electrochemical performance of
- 17 oxygen-terminated polycrystalline boron-doped diamond electrodes, Analytical
- 18 chemistry 85(15) (2013) 7230-7240.
- 19 [17] N. Yang, J.S. Foord, X. Jiang, Diamond electrochemistry at the nanoscale: A
- 20 review, Carbon 99 (2016) 90-110.

- 1 [18] S. Garcia-Segura, E.V. Dos Santos, C.A. Martínez-Huitle, Role of sp³/sp² ratio on
- 2 the electrocatalytic properties of boron-doped diamond electrodes: a mini review,
- 3 Electrochemistry Communications 59 (2015) 52-55.
- 4 [19] H.E. Hussein, H. Amari, J.V. Macpherson, Electrochemical synthesis of
- 5 nanoporous platinum nanoparticles using laser pulse heating: application to methanol
- 6 oxidation, ACS Catalysis 7(10) (2017) 7388-7398.
- 7 [20] D. Guo, R. Shibuya, C. Akiba, S. Saji, T. Kondo, J. Nakamura, Active sites of
- 8 nitrogen-doped carbon materials for oxygen reduction reaction clarified using model
- 9 catalysts, Science 351(6271) (2016) 361-365.
- 10 [21] Y. Jia, L. Zhang, L. Zhuang, H. Liu, X. Yan, X. Wang, J. Liu, J. Wang, Y. Zheng,
- 11 Z. Xiao, Identification of active sites for acidic oxygen reduction on carbon catalysts
- with and without nitrogen doping, Nature Catalysis 2(8) (2019) 688-695.
- 13 [22] V.N. Mochalin, O. Shenderova, D. Ho, Y. Gogotsi, The properties and applications
- of nanodiamonds, Nature nanotechnology 7(1) (2012) 11-23.
- 15 [23] Y. Lin, D. Su, Fabrication of nitrogen-modified annealed nanodiamond with
- 16 improved catalytic activity, ACS nano 8(8) (2014) 7823-7833.
- 17 [24] Y. Liu, S. Chen, X. Quan, H. Yu, Efficient electrochemical reduction of carbon
- 18 dioxide to acetate on nitrogen-doped nanodiamond, Journal of the American Chemical
- 19 Society 137(36) (2015) 11631-11636.
- 20 [25] H. Wang, Y.-K. Tzeng, Y. Ji, Y. Li, J. Li, X. Zheng, A. Yang, Y. Liu, Y. Gong, L.
- 21 Cai, Synergistic enhancement of electrocatalytic CO₂ reduction to C2 oxygenates at

- 1 nitrogen-doped nanodiamonds/Cu interface, Nature nanotechnology 15(2) (2020) 131-
- 2 137.
- 3 [26] J. Zhang, Z. Zhao, Z. Xia, L. Dai, A metal-free bifunctional electrocatalyst for
- 4 oxygen reduction and oxygen evolution reactions, Nature nanotechnology 10(5) (2015)
- 5 444-452.
- 6 [27] C. Zhang, X. Wang, Q. Liang, X. Liu, Q. Weng, J. Liu, Y. Yang, Z. Dai, K. Ding,
- 7 Y. Bando, Amorphous phosphorus/nitrogen-doped graphene paper for ultrastable
- 8 sodium-ion batteries, Nano letters 16(3) (2016) 2054-2060.
- 9 [28] Y. Zhao, N. Yang, H. Yao, D. Liu, L. Song, J. Zhu, S. Li, L. Gu, K. Lin, D. Wang,
- 10 Stereodefined codoping of sp-N and S atoms in few-layer graphdiyne for oxygen
- evolution reaction, Journal of the American Chemical Society 141(18) (2019) 7240-
- 12 7244.
- 13 [29] Y. Liu, Y. Zhang, K. Cheng, X. Quan, X. Fan, Y. Su, S. Chen, H. Zhao, Y. Zhang,
- 14 H. Yu, Selective electrochemical reduction of carbon dioxide to ethanol on a boron-and
- nitrogen-Co-doped nanodiamond, Angewandte Chemie 129(49) (2017) 15813-15817.
- 16 [30] Y. Liu, S. Chen, X. Quan, H. Yu, H. Zhao, Y. Zhang, G. Chen, Boron and nitrogen
- 17 codoped nanodiamond as an efficient metal-free catalyst for oxygen reduction reaction,
- 18 The Journal of Physical Chemistry C 117(29) (2013) 14992-14998.
- 19 [31] N. Yang, S. Yu, J.V. Macpherson, Y. Einaga, H. Zhao, G. Zhao, G.M. Swain, X.
- 20 Jiang, Conductive diamond: synthesis, properties, and electrochemical applications,
- 21 Chemical Society Reviews 48(1) (2019) 157-204.

- 1 [32] J. Xu, N. Yang, S. Heuser, S. Yu, A. Schulte, H. Schönherr, X. Jiang, Achieving
- 2 ultrahigh energy densities of supercapacitors with porous titanium carbide/boron-doped
- 3 diamond composite electrodes, Advanced Energy Materials 9(17) (2019) 1803623.
- 4 [33] J. Hees, A. Kriele, O.A. Williams, Electrostatic self-assembly of diamond
- 5 nanoparticles, Chemical Physics Letters 509(1-3) (2011) 12-15.
- 6 [34] O.A. Williams, Nanocrystalline diamond, Diamond and Related Materials 20(5-6)
- 7 (2011) 621-640.
- 8 [35] O.A. Williams, O. Douhéret, M. Daenen, K. Haenen, E. Ōsawa, M. Takahashi,
- 9 Enhanced diamond nucleation on monodispersed nanocrystalline diamond, Chemical
- 10 Physics Letters 445(4-6) (2007) 255-258.
- 11 [36] T.S. Mathis, N. Kurra, X. Wang, D. Pinto, P. Simon, Y. Gogotsi, Energy storage
- 12 data reporting in perspective—guidelines for interpreting the performance of
- 13 electrochemical energy storage systems, Advanced Energy Materials 9(39) (2019)
- 14 1902007.
- 15 [37] W. Lu, J. Shen, P. Zhang, Y. Zhong, Y. Hu, X.W. Lou, Construction of CoO/Co-
- 16 Cu-S Hierarchical Tubular Heterostructures for Hybrid Supercapacitors, Angewandte
- 17 Chemie International Edition 58(43) (2019) 15441-15447.
- 18 [38] T. Brezesinski, J. Wang, S.H. Tolbert, B. Dunn, Ordered mesoporous α-MoO 3
- 19 with iso-oriented nanocrystalline walls for thin-film pseudocapacitors, Nature materials
- 20 9(2) (2010) 146-151.

- 1 [39] T. Liu, D. Raabe, Influence of nitrogen doping on growth rate and texture evolution
- 2 of chemical vapor deposition diamond films, Applied Physics Letters 94(2) (2009)
- 3 021119.
- 4 [40] K.N. Kudin, B. Ozbas, H.C. Schniepp, R.K. Prud'Homme, I.A. Aksay, R. Car,
- 5 Raman spectra of graphite oxide and functionalized graphene sheets, Nano letters 8(1)
- 6 (2008) 36-41.
- 7 [41] J.-C. Arnault, X-ray Photoemission Spectroscopy applied to nanodiamonds: From
- 8 surface chemistry to in situ reactivity, Diamond and Related Materials 84 (2018) 157-
- 9 168.
- 10 [42] J. Xu, Y. Yokota, R.A. Wong, Y. Kim, Y. Einaga, Unusual electrochemical
- 11 properties of low-doped boron-doped diamond electrodes containing sp² carbon,
- Journal of the American Chemical Society 142(5) (2020) 2310-2316.
- 13 [43] O.A. Williams, Ultrananocrystalline diamond for electronic applications,
- 14 Semiconductor science and technology 21(8) (2006) R49.
- 15 [44] P. Achatz, O.A. Williams, P. Bruno, D. Gruen, J. Garrido, M. Stutzmann, Effect
- 16 of nitrogen on the electronic properties of ultrananocrystalline diamond thin films
- 17 grown on quartz and diamond substrates, Physical Review B 74(15) (2006) 155429.
- 18 [45] Z.J. Ayres, A.J. Borrill, J.C. Newland, M.E. Newton, J.V. Macpherson, Controlled
- 19 sp2 functionalization of boron doped diamond as a route for the fabrication of robust
- and Nernstian pH electrodes, Analytical chemistry 88(1) (2016) 974-980.

- 1 [46] S. Yu, N. Yang, H. Zhuang, S. Mandal, O.A. Williams, B. Yang, N. Huang, X.
- 2 Jiang, Battery-like supercapacitors from diamond networks and water-soluble redox
- 3 electrolytes, Journal of Materials Chemistry A 5(4) (2017) 1778-1785.
- 4 [47] Z. Ling, Z. Wang, M. Zhang, C. Yu, G. Wang, Y. Dong, S. Liu, Y. Wang, J. Qiu,
- 5 Sustainable synthesis and assembly of biomass-derived B/N co-doped carbon
- 6 nanosheets with ultrahigh aspect ratio for high-performance supercapacitors, Advanced
- 7 functional materials 26(1) (2016) 111-119.

- 8 [48] Z.S. Wu, A. Winter, L. Chen, Y. Sun, A. Turchanin, X. Feng, K. Müllen, Three-
- 9 dimensional nitrogen and boron co-doped graphene for high-performance all-solid-
- state supercapacitors, Advanced Materials 24(37) (2012) 5130-5135.

Supporting Information

2	
3	Electrochemistry of Nitrogen and Boron
4	Bi-element Incorporated Diamond Films
5	Tianxiao Guo, ^a Nianjun Yang, ^{a*} Bing Yang, ^b Anna Schulte, ^c Qun Jin, ^a Ulrike Koch, ^d
6	Rainer Bornemann, e Soumen Mandal, f Carsten Engelhard, d Oliver A. Williams, f
7	Holger Schönherr, ^c and Xin Jiang ^{a, *}
8	^a Institute of Materials Engineering, University of Siegen, Siegen 57076, Germany
9	^b Shenyang National Laboratory for Materials Science, Institute of Metal Research
10	(IMR), Chinese Academy of Science (CAS), No. 72 Wenhua Road, Shenyang
11	110016, China
12	^c Physical Chemistry I, Department of Chemistry and Biology and Research Center of
13	Micro and Nanochemistry and Engineering (C μ), University of Siegen, Siegen 57075,
14	Germany
15	^d Analytical Chemistry, Department of Chemistry and Biology and Research Center
16	of Micro and Nanochemistry and Engineering (Cµ), University of Siegen, Siegen
17	57075, Germany
18	^e Institute for High Frequency and Quantum Electronics, School of Science and
19	Technology, University of Siegen, Siegen, Siegen 57076, Germany
20	^f School of Physics and Astronomy, Cardiff University, Cardiff CF24 3AA, UK

1 Supporting Tables

- 2 Table S1. CVD growth parameters of the boron-doped diamond (BDD) films as well
- 3 as the nitrogen and boron bi-element incorporated diamond (NBD) films.

	BDD	NBD				
Incubation						
Forward power (kW)	4.8	4.8				
Chamber pressure (Torr)	45	45				
Duration times (min)	7	7				
CH ₄ (seem)	15	15				
$H_2(sccm)$	185	82				
TMB (sccmppm)*	0.22000	<u>0.4</u> 2000				
N ₂ (sccm)		3				
Growth						
Forward power (kW)	4.8	4.8				
Chamber pressure (Torr)	45	45				
Duration times (min)	1435	1203				
CH ₄ (sccm)	3	3				
$H_2(sccm)$	277	254				
TMB (sccm)	20	40				
N ₂ (sccm)		3				

4 * The TMB flow has been calculated based on total flow of gas mix containing

2000ppm TMB diluted in H2,

5

6

 $\textbf{Formatted:} \ \mathsf{Font:} \ (\mathsf{Default}) \\ \mathsf{TimesNewRoman}, \\ \mathsf{Bold}$

Formatted: Font: (Default) Times New Roman, Bold

Table S2. Relative abundance of the carbon components in the BDD and NBD films.*

	sp ² C	sp ³ C	C-O	C=O	C-N	sp ² C/sp ³ C
NBD	3.7	31.0	34.0	28.9	2.4	11.9
BDD	2.0	52.0	32.3	13.6		3.8

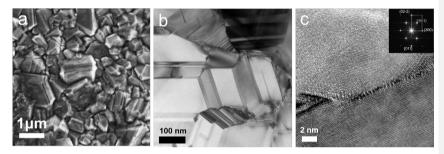
^{*} These atomic ratios were estimated from their high resolution C1s XPS spectra

4 Supporting Figures

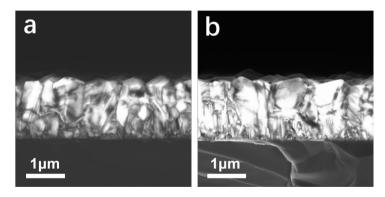
3

5

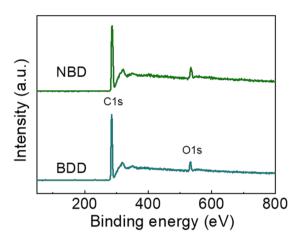
9



- 6 Figure S1. (a) SEM, (b) low-magnification TEM and (c) HRTEM images of the BDD
- 7 film. The inset in (c) is the corresponding fast Fourier transformation (FFT) of the
- 8 HRTEM image.

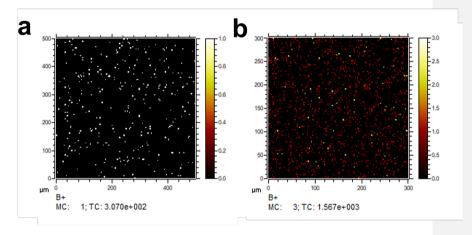


10 Figure S2. The cross-sectional SEM images of the (a) NBD and (b) BDD films.



2 **Figure S3.** XPS survey spectra for the NBD and BDD films.

1



4 Figure S4. SIMS mapping of boron atoms doped in the BDD film (a) direct and (b)

- 5 after 30 sec sputtering with Argon for cleaning the surface in the positive mode (MC
- 6 max counts per pixel, TC total counts).

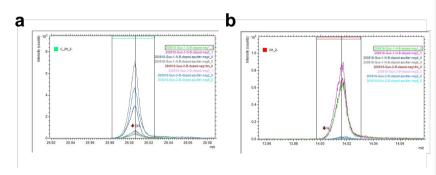


Figure S5. Spectra of the (a) NBD and (b) BDD films in the negative mode. The m/z

3 ratios of N, CH_2 , CN, and C_2H_2 are 14,003, 14,0162, 26,0036 and 26,0162, respectively.

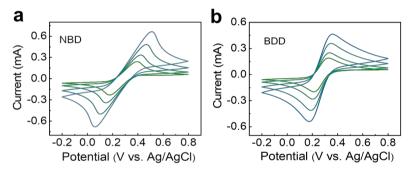


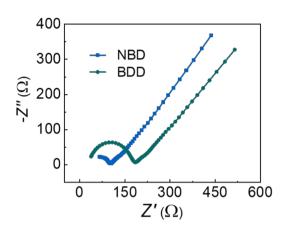
Figure S6. CVs of 0.05 M Fe(CN)₆^{3-/4-} in 1.0 M NaSO₄ on the (a) NBD and (b) BDD

7 electrodes at the scan rates of 100, 50, 20, and 10 mV s⁻¹.

1

4

5



2 Figure S7. Nyquist plots of the NBD and BDD electrodes in 1.0 M NaSO₄ solution

containing $0.05 \text{ M Fe}(\text{CN})_6^{3-/4}$.

1

4

5

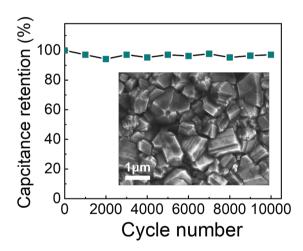


Figure S8. Capacitance retention of a BDD electrode at a current density of 8 mA cm

6 ². The inset shows the SEM image of a BDD electrode after 10000 GCD cycles.